



ZXMS6005DG 60V N-CHANNEL SELF PROTECTED ENHANCEMENT MODE INTELLIFETTM MOSFET

SUMMARY

Continuous drain source voltage 60 V

On-state resistance 200 m Ω

Nominal load current $(V_{IN} = 5V)$ 2 A

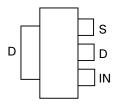
Clamping Energy 490 mJ



SOT223 Package

DESCRIPTION

The ZXMS6005DG is a self protected low side MOSFET with logic level input. It integrates over-temperature, over-current, over-voltage (active clamp) and ESD protected logic level functionality. The ZXMS6005DG is ideal as a general purpose switch driven from 3.3V or 5V microcontrollers in harsh environments where standard MOSFETs are not rugged enough.



FEATURES

- Compact high power dissipation package
- Low input current
- Logic Level Input (3.3V and 5V)
- Short circuit protection with auto restart
- Over voltage protection (active clamp)
- Thermal shutdown with auto restart
- Over-current protection
- Input Protection (ESD)
- High continuous current rating

ORDERING INFORMATION

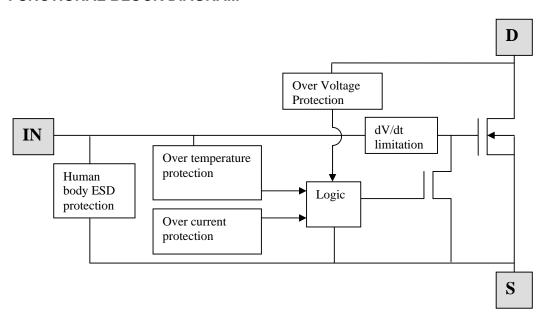
DEVICE	PART	REEL SIZE	TAPE WIDTH	QUANTITY PER
	MARK	(inches)	(mm)	REEL
ZXMS6005DGTA	ZXMS 6005D	7	12 embossed	1,000 units

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FUNCTIONAL BLOCK DIAGRAM



APPLICATIONS AND INFORMATION

- Especially suited for loads with a high in-rush current such as lamps and motors.
- All types of resistive, inductive and capacitive loads in switching applications.
- μC compatible power switch for 12V DC applications.
- Automotive rated.
- Replaces electromechanical relays and discrete circuits.
- Linear Mode capability the current-limiting protection circuitry is designed to de-activate
 at low V_{DS} to minimise on state power dissipation. The maximum DC operating current is
 therefore determined by the thermal capability of the package/board combination, rather
 than by the protection circuitry. This does not compromise the product's ability to selfprotect at low V_{DS}.

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ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	LIMIT	UNIT
Continuous Drain-Source Voltage	V_{DS}	60	V
Drain-Source Voltage for short circuit protection	$V_{DS(SC)}$	24	V
Continuous Input Voltage	V _{IN}	-0.5 +6	V
Continuous Input Current	I _{IN}		mA
-0.2V≤V _{IN} ≤6V V _{IN} <-0.2V or V _{IN} >6V		No limit I _{IN} ≤2	
Operating Temperature Range	T _j ,	-40 to +150	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C
Power Dissipation at T _A =25°C (a)	P _D	1.3	W
Linear Derating Factor		10.4	mW/°C
Power Dissipation at T _A =25°C (b)	P_D	3.0	W
Linear Derating Factor		24	mW/°C
Pulsed Drain Current @ V _{IN} =3.3V	I _{DM}	5	А
Pulsed Drain Current @ V _{IN} =5V	I _{DM}	6	А
Continuous Source Current (Body Diode) (a)	I _S	2.5	А
Pulsed Source Current (Body Diode)	I _{SM}	10	А
Unclamped single pulse inductive energy, Tj=25°C, I_D =0.5A, V_{DD} =24V	E _{AS}	490	mJ
Electrostatic Discharge (Human Body Model)	V_{ESD}	4000	V
Charged Device Model	V _{CDM}	1000	V

THERMAL RESISTANCE

THERMAE REGIOTANGE			
PARAMETER	SYMBOL	VALUE	UNIT
Junction to Ambient (a)	$R_{\theta JA}$	96	°C/W
Junction to Ambient (b)	$R_{\theta JA}$	42	°C/W
Junction to Case (c)	$R_{\theta JC}$	12	°C/W

NOTES

- (a) For a device surface mounted on 15mm x 15mm single sided 1oz weight copper on 1.6mm FR4 board, in still air conditions.
- (b) For a device surface mounted on 50mm x 50mm single sided 2oz weight copper on 1.6mm FR4 board, in still air conditions.
- (c) Thermal resistance from junction to the mounting surfaces of the drain pins.



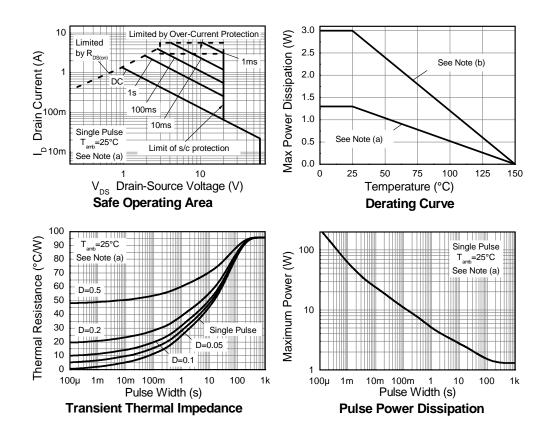


RECOMMENDED OPERATING CONDITIONS

The ZXMS6005DG is optimised for use with µC operating from 3.3V and 5V supplies.

Symbol	Description	Min	Max	Units
V_{IN}	Input voltage range	0	5.5	V
T _A	Ambient temperature range	-40	125	°C
V _{IH}	High level input voltage for MOSFET to be on	3	5.5	V
V_{IL}	Low level input voltage for MOSFET to be off	0	0.7	V
V_P	Peripheral supply voltage (voltage to which load is referred)	0	24	V

CHARACTERISTICS







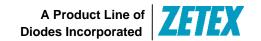
ELECTRICAL CHARACTERISTICS (at T_{amb} = 25°C unless otherwise stated).

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT	CONDITIONS
Static Characteristics		•	•	•	•	
Drain-Source Clamp Voltage	V _{DS(AZ)}	60	65	70	V	I _D =10mA
Off state Drain Current	I _{DSS}			1	μΑ	V _{DS} =12V, V _{IN} =0V
Off state Drain Current	I _{DSS}			2	uA	V_{DS} =36V, V_{IN} =0V
Input Threshold Voltage	$V_{IN(th)}$	0.7	1	1.5	V	$V_{DS}=V_{GS}$, $I_{D}=1mA$
Input Current	I _{IN}		60	100	μΑ	V _{IN} =+3V
Input Current	I _{IN}		120	200	μΑ	V _{IN} =+5V
Input Current while over temperature active				300	μА	V _{IN} =+5V
Static Drain-Source On-State Resistance	R _{DS(on)}		170	250	mΩ	V_{IN} =+3 V , I_D =1 A
Static Drain-Source On-State Resistance	R _{DS(on)}		150	200	mΩ	$V_{IN}=+5V$, $I_D=1A$
Continuous Drain Current (a)	I _D	1.4			А	V _{IN} =3V; T _A =25°C
Continuous Drain Current (a)	I _D	1.6			Α	V _{IN} =5V; T _A =25°C
Continuous Drain Current (b)	I _D	1.9			Α	V _{IN} =3V; T _A =25°C
Continuous Drain Current (b)	I _D	2.0			Α	V _{IN} =5V; T _A =25°C
Current Limit (d)	I _{D(LIM)}	2.2	5		Α	V _{IN} =+3V,
Current Limit (d)	I _{D(LIM)}	3.3	7		Α	V _{IN} =+5V
Dynamic Characteristics						
Turn On Delay Time	t _{d(on)}		6		μS	$V_{DD}=12V, I_{D}=1A,$
Rise time	t _r		14		μS	V _{GS} =5V
Turn Off Delay Time	t _{d(off)}		34		μS	_
Fall Time	f_f		19		μS	

Notes:

(d) The drain current is restricted only when the device is in saturation (see graph 'typical output characteristic'). This allows the device to be used in the fully on state without interference from the current limit. The device is fully protected at all drain currents, as the low power dissipation generated outside saturation makes current limit unnecessary.





PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT	CONDITIONS
Over-temperature Protection						
Thermal Overload Trip Temperature (e)	T_{JT}	150	175		°C	
Thermal hysteresis (e)			10		°C	

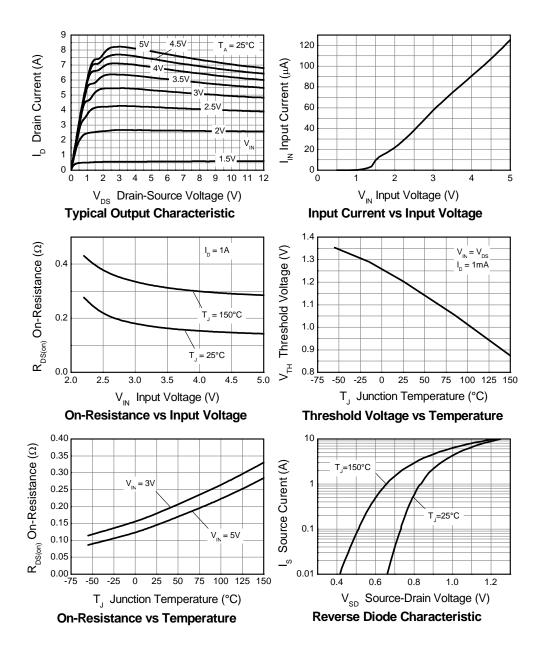
Note:

(e) Over-temperature protection is designed to prevent device destruction under fault conditions. Fault conditions are considered as "outside" normal operating range, so this part is not designed to withstand over-temperature for extended periods..

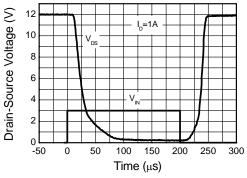


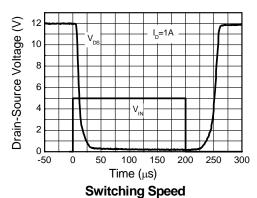


TYPICAL CHARACTERISTICS

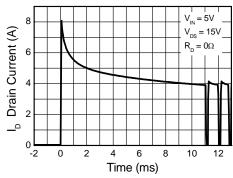






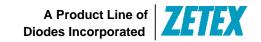


Switching Speed



Typical Short Circuit Protection





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